

2MBI300HJ-120-50

IGBT Modules

Power Module (V series) 1200V / 300A / 2-in-1 package

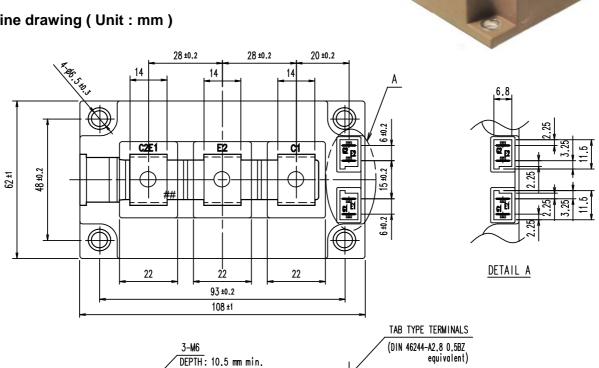
■ Features

High speed switching Voltage drive Low Inductance module structure

■ Applications

Soft-switching Application Industrial machines, such as Welding machines

■ Outline drawing (Unit:mm)

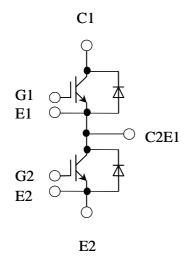


30.9 ±0.5

Weight: 370g (typ.)

■ Equivalent Circuit

30.5±0.5



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■ Absolute Maximum Ratings (at Tc= 25°C unless otherwise specified)

	Items	Symbols	Cond	litions	Maximum Ratings	Units
Collector-E	mitter voltage	V_{CES}			1200	V
Gate-Emitt	ter voltage	V_{GES}			±20	V
		$I_{\rm C}$ Continuous $T_{\rm C}=60^{\circ}{\rm C}$ 300	300			
		I _C	Continuous T _C =25°C			1
Collector of	urrent	I _C pulse	1ms		600	Α
					400	
			1ms		800	
Collector power dissipation		P _C	1 device		1950	W
Junction temperature		T _j			150	
Case temperature		T _c			125	°C
Storage temperature		T _{stg}			-40 ~ 125	
Isolation	between terminal and copper base	V _{iso}	AC: 1min.		2500	VAC
voltage	(*1)	v iso	AC. IIIIII.		2500	VAC
Screw	Mounting (*2)	-			6.0	N m
Torque	Terminals (*3)	-			5.0	INIII

(*1) All terminals should be connected together during the test.

(*2) Recommendable Value: 3.0-6.0 Nm (M5 or M6)

(*3) Recommendable Value: 2.5-5.0 Nm (M6)

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■ Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items	Symbols	Condition		Ch	aracterist	ics	Units	
items	Symbols	Condition	15	min.	typ.	Units		
Zero gate voltage Collector current	I _{CES}	VGE=0V, VCE=1200)V	-	-	4.0	mA	
Gate-Emitter leakage current	I _{GES}	VCE=0V, VGE=±20\	/	-	-	800	nA	
Gate-Emitter threshold voltage	$V_{GE(th)}$	VCE=20V, Ic=300m/		5.7	6.2	6.7	V	
	$V_{CE(sat)}$	VGE=15V, Ic=300A	T _i =25°C	ı	3.40	3.70		
Collector-Emitter	(terminal)	VGL-13V, 10-300A	T _i =125°C	ı	4.20	-	V	
saturation voltage	$V_{CE(sat)}$	VGE=15V, Ic=300A	T _i =25°C	-	3.20	3.50	V	
	(chip)	VGL-13V, 10-300A	T _i =125°C	-	4.00	-		
Internal gate	$R_{G(int)}$	-		ı	0.5	-	Ω	
Input capacitance	C _{ies}	V _{CE} =10V, V _{GE} =0V, f	=1MHz	-	36.0	-	nF	
	t _{on}			-	250	-		
Turn-on time	t _r	$Vcc=600V$ $I_C=$: 300A	-	180	-		
	t _{r(i)}	V_{GE} = ±15V R_{G} =	: 3.3Ω	-	40	-	nsec	
Turn-off time	t _{off}	T _i = 125°C L _s =	: 30nH	-	300	-		
rum-on time	tf			-	50	-		
	V_{F}	\/CE-0\/ IE-400A	T _i =25°C	-	1.85	2.30		
Forward on voltage	(terminal)	VGE=0V,IF=400A	T _i =125°C	-	2.00	-	V	
	V _F	VOE 0V/IE 400A	T _i =25°C	-	1.70	2.15		
	(chip)	VGE=0V,IF=400A	T _i =125°C	-	1.85	-		
Reverse recovery time	t _{rr}	IF=400A		-	130	-	nsec	

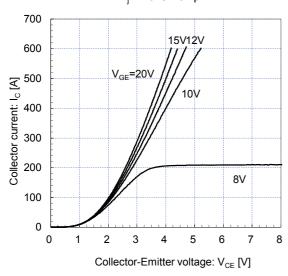
5. Thermal resistance characteristics

Items	Symbols	Conditions Characterist		ics	Linita	
items	Symbols	Conditions	min.	min. typ. max	max.	Ullits
Thermal resistance(1dev	R	IGBT	-	-	0.064	
mermanesistance (ruev	$R_{th(j-c)}$	FWD	-	-	0.110	Units °C/W
Contact thermal	D	with Thermal Compound		0.0125		C/VV
resistance	$R_{th(c-f)}$	with Thermal Compound	-	0.0123	0.064 0.110	

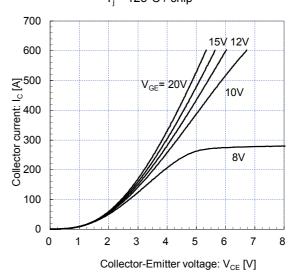
^(*1) This is the value which is defined mounting on the additional cooling fin with thermal compound.

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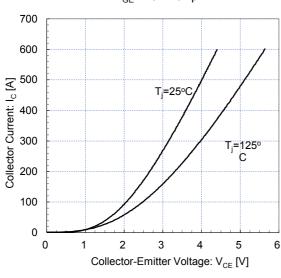
Collector current vs. Collector-Emitter voltage $T_i = 25^{\circ}C$ / chip



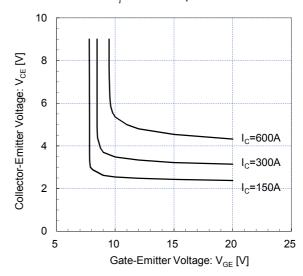
Collector current vs. Collector-Emitter voltage (typ.) $T_i = 125^{\circ}\text{C}$ / chip



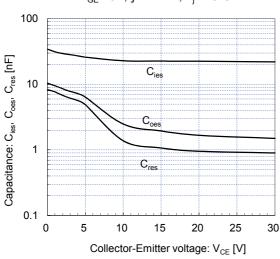
Collector current vs. Collector-Emitter voltage V_{GE} = 15V / chip



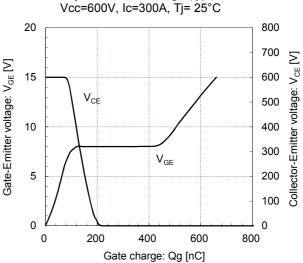
Collector-Emitter voltage vs. Gate-Emitter voltage $T_i = 25^{\circ}C$ / chip



Capacitance vs. Collector-Emitter Voltage V_{GE} = 0V, f= 1MHz, T_j = 25°C

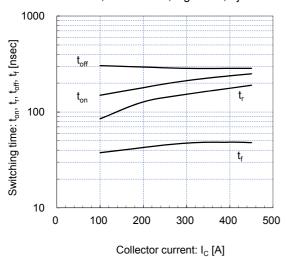


Dynamic Gate Charge (typ.)

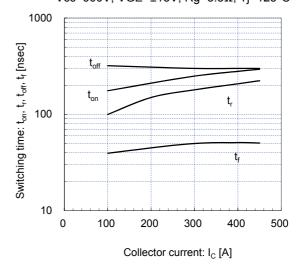


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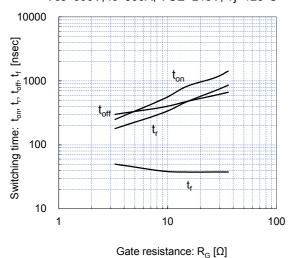
Switching time vs. Collector current (typ.) Vcc=600V, VGE=±15V, Rg=3.3Ω, Tj=25°C



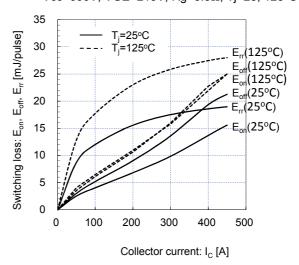
Switching time vs. Collector current (typ.) Vcc=600V, VGE=±15V, Rg=3.3Ω, Tj=125°C



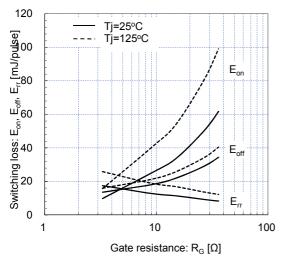
Switching time vs. Gate resistance (typ.) Vcc=600V, Ic=300A, VGE=±15V, Tj=125°C



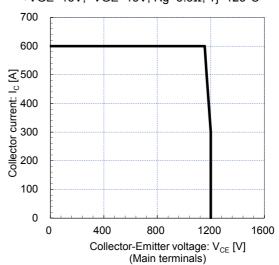
Switching loss vs. Collector current (typ.) Vcc=600V, VGE=±15V, Rg=3.3Ω, Tj=25, 125°C



Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=300A, VGE=±15V, Tj=25, 125°C



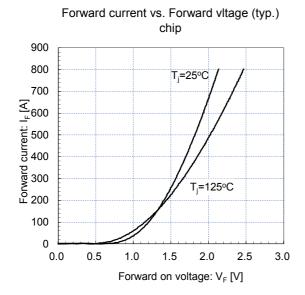
Reverse bias safe operating area (max.) +VGE=15V, -VGE=15V, Rg=3.3Ω, Tj=125°C

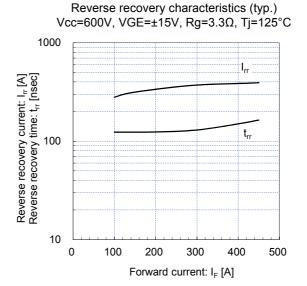


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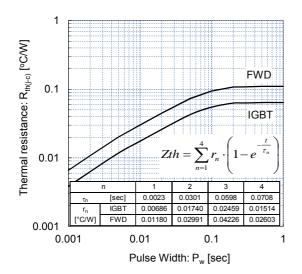


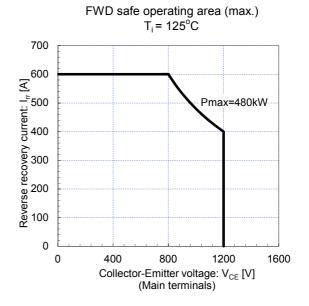
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Transient thermal resistance (max.)





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